

April 2009

FOD0708 Single Channel CMOS Optocoupler, FOD0738 Dual Channel CMOS Optocoupler

Features

- +5V CMOS compatibility
- 15ns typical pulse width distortion
- 30ns max. pulse width distortion
- 40ns max. propagation delay skew
- High speed: 15 MBd
- 60ns max. propagation delay
- 10kV/µs minimum common mode rejection
- -40°C to 100°C temperature range
- UL approved (file #E90700)

Applications

- Line receivers
- Pulse transformer replacement
- Output interface to CMOS-LSTTL-TTL
- Wide bandwidth analog coupling

General Description

The FOD0708 and FOD0738 optocouplers consist of an AlGaAs LED optically coupled to a high speed transimpedance amplifier and voltage comparator. These optocouplers utilize the latest CMOS IC technology to achieve outstanding performance with very low power consumption. The devices are housed in a compact 8-pin SOIC package for optimum mounting density.



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Absolute Maximum Ratings ($T_A = 25^{\circ}C$ unless otherwise specified) Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter			Min.	Max.	Units
Τ _S	Storage Temperature			-40	+125	°C
T _A	Ambient Operating Temperature	6		-40	+100	°C
V _{DD}	Supply Voltages			0	6	Volts
Vo	Output Voltage			-0.5	V _{DD} + 0.5	Volts
Ι _Ο	Average Output Current				2	mA
١ _F	Average Forward Input Current				20	mA
	Lead Solder Temperature		260°C for 10 sec., 1.6 mm below seating plane			
	Solder Reflow Temperature Profile		See Solder Reflow Temperature Profile Section			rofile Section
	LED Power Dissipation					
	Single Channel			40mW (dera	te above 95°C, 1.4	4mW/°C)
	Dual Channel		40n	nW per channe	I (derate above 90	°C, 1.2mW/°C)
	Detector Power Dissipation					
	Single Channel			85mW (dera	te above 75°C, 1.8	BmW/°C)
	Dual Channel 65mW per channel (derate above 90°C, 2		°C, 2.0mW/°C)			

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to absolute maximum ratings.

Symbol	Parameter	Min.	Max.	Units
T _A	Ambient Operating Temperature	-40	+100	°C
V _{DD}	Supply Voltages	4.5	5.5	Volts
١ _F	Input Current (ON)	10	16	mA

Electrical Characteristics ($T_A = -40^{\circ}C$ to $+100^{\circ}C$) and $4.5 V \le V_{DD} \le 5.5 V$

Symbol	Parameter		Test Conditions	Min.	Тур.*	Max.	Units	Fig.
V _F	Input Forward Voltage		I _F = 12mA	1.3	1.45	1.8	V	9
BV _R	Input Reverse Breakdown Voltage		I _R = 10μΑ	5			V	
V _{OH}	Logic High Output Voltage		$I_{\rm F} = 0, \ I_{\rm O} = -20\mu{\rm A}$	4.0	5.0		V	
V _{OL}	Logic Low Output Voltage		I _F = 12mA, I _O = 20μA		0.01	0.1	V	
I _{TH}	Input Threshold Current	(FOD0708) (FOD0738)	I _{OL} = 20μΑ		4.0 4.4	8.2 8.2	mA	1,5
I _{DDL}	Logic Low Output Supply Current	(FOD0708) (FOD0738)	I _F = 12mA		3.4 6.9	14.0 18.0	mA	3,7
I _{DDH}	Logic High Output Supply Current	(FOD0708) (FOD0738)	I _F = 0		3.7 7.5	11.0 15.0	mA	4,8

All typicals at T_A = 25°C and V_{DD} = 5V unless otherwise noted.

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Symbol	Parameter	Test Conditions		Min.	Тур.*	Max.	Units
t _{PHL}	Propagation Delay Time to Logic Low Output	I _F = 12mA, C _L = 15pF CMOS Signal Levels (Note 1) (Fig. 10)		20		60	ns
t _{PLH}	Propagation Delay Time to	$I_{F} = 12mA, C_{L} = 15pF$	FOD0708	13		60	ns
	Logic High Output	CMOS Signal Levels, (Note 1) (Fig. 10)	FOD0738	11		60	
PW	Pulse Width			100			ns
PWD	Pulse Width Distortion	I _F = 12mA, C _L = 15pF, CMOS Signal Levels (Note 2)		0		30	ns
t _{PSK}	Propagation Delay Skew	I _F = 12mA, C _L = 15pF, CMOS Signal Levels (Note 3)				40	ns
t _R	Output Rise Time (10%–90%)	I _F = 12mA, C _L = 15pF, CMOS Signal Levels			12		ns
t _F	Output Fall Time (90%–10%)	I _F = 12mA, C _L = 15pF, CMOS Signal Levels			8		ns
I CM _H I	Common Mode Transient Immunity at Logic High Output	V _{CM} = 1000V, T _A = 25°C, I _F = 0mA, (Note 4) (Fig. 11)		25	50		kV/µs
I CM _L I	Common Mode Transient Immunity at Logic Low Output	V_{CM} = 1000V, T_A = 25°C, I_F = 12mA, (Note 5) (Fig. 11)		25	50		kV/µs

Switching Characteristics Over recommended temperature ($T_A = -40^{\circ}C$ to +100°C) and $4.5 V \le V_{-1} \le 5.5 V$ All typical specifications are at $T_{-1} = 25^{\circ}C$. $V_{-1} = -15 V$

*All typicals at $T_A = 25^{\circ}C$ and $V_{DD} = 5V$ unless otherwise noted.

Isolation Characteristics (T_A = -40°C to +100°C Unless otherwise specified.)

Characteristics	Test Conditions	Symbol	Min	Тур.*	Max	Unit
Input-Output Insulation Leakage Current	Relative humidity = 45%, $T_A = 25^{\circ}C$, t = 5s, $V_{I-O} = 3000 \text{ VDC}$ (Note 6)	I _{I-O}			1.0	μA
Withstand Insulation Test Voltage	$I_{I-O} \le 10\mu A, R_H < 50\%, T_A = 25^{\circ}C, t = 1 min. (Note 6)$	V _{ISO}	2500			V _{RMS}
Resistance (Input to Output)	V _{I-O} = 500V (Note 6)	R _{I-O}		10 ¹²		Ω
Capacitance (Input to Output)	f = 1MHz (Note 6)	C _{I-O}		0.6		pF

*All typical values are at $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$

Notes:

- Propagation delay time, high to low (t_{PHL}), is measured from the 50% level on the rising edge of the input pulse to the 2.5V level of the falling edge of the output voltage signal. Propagation delay time, low to high (t_{PLH}), is measured from the 50% level on the falling edge of the input pulse to the 2.5V level of the rising edge of the output voltage signal.
- Pulse width distoration is defined as the absolute difference between the high to low and low to high propagation delay times, | t_{PHL} - t_{PLH} |.
- Propagation delay skew, t_{PSK}, is defined as the worst case difference in t_{PHL} or t_{PLH} between units within the recommended operating range of the device.
- CM_H The maximum tolerated rate of rise of the common mode voltage to ensure the output will remain in the high state, (i,e., V_{OUT} > 2.0V) Measured in kilovolts per microsecond (kV/µs).
- CM_L The maximum tolerated rate of fall of the common mode voltage to ensure the output will remain in the low state, (i,e., V_{OUT} < 0.8V). Measured in kilovolts per microsecond (kV/µs).
- Isolation voltage, V_{ISO}, is an internal device dielectric breakdown rating. For this test, pins 1,2,3,4 are common, and pins 5,6,7,8 are common.



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Ordering Information

Option	Order Entry Identifier	Description
No Suffix	FOD0708	Shipped in tubes (50 units per tube)
R2	FOD0708R2	Tape and Reel (2500 units per reel)

Marking Information



Definiti	ons
1	Fairchild logo
2	Device number
3	VDE mark (Note: Only appears on parts ordered with VDE option – See order entry table)
4	One digit year code, e.g., '5'
5	Two digit work week ranging from '01' to '53'
6	Assembly package code





Profile Freature	Pb-Free Assembly Profile
Temperature Min. (Tsmin)	150°C
Temperature Max. (Tsmax)	200°C
Time (t _S) from (Tsmin to Tsmax)	60–120 seconds
Ramp-up Rate (t _L to t _P)	3°C/second max.
Liquidous Temperature (T _L)	217°C
Time (t_L) Maintained Above (T_L)	60–150 seconds
Peak Body Package Temperature	260°C +0°C / -5°C
Time (t _P) within 5°C of 260°C	30 seconds
Ramp-down Rate (T _P to T _L)	6°C/second max.
Time 25°C to Peak Temperature	8 minutes max.

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PRODUCT STATUS DEFINITIONS

Definition of Terms				
Datasheet Identification	Product Status	Definition		
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.		
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.		
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